

3A, 600V Standard Surface Mount Rectifier

FEATURES

- AEC-Q101 qualified
- Glass passivated chip junction
- Ideal for automated placement
- Low profile package
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen Free

APPLICATION	S
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- Freewheeling
- Snubber
- DC/DC converters
- Automotive application

MECHANICAL DATA

- Case: SOD-128
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: Indicated by cathode band
- Weight: 0.027g (approximately)

KEY PARAMETERS			
PARAMETER	VALUE	UNIT	
lF	3	А	
V _{RRM}	600	V	
IFSM	50	А	
Тј мах	150	°C	
Package	SOD-128		
Configuration	Single die		



ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	S3JFSH	UNIT
Marking code on the device			S3JFS	
Repetitive peak reverse voltage	;	Vrrm	600	V
Reverse voltage, total rms valu	e	V _{R(RMS)}	420	V
Forward current		IF	3	А
Surge peak forward current,	t = 8.3ms	1	50	А
single half sine-wave superimposed on rated load	t = 1.0ms	IFSM	140	А
Junction temperature		TJ	-55 to +150	°C
Storage temperature		Tstg	-55 to +150	°C



THERMAL PERFORMANCE			
PARAMETER	SYMBOL	ТҮР	UNIT
Junction-to-lead thermal resistance	R _{θJL}	14	°C/W
Junction-to-ambient thermal resistance	Reja	74	°C/W
Junction-to-case thermal resistance	Rejc	20	°C/W

Thermal Performance Note: Units mounted on PCB (5mm x 5mm Cu pad test board)

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	ТҮР	MAX	UNIT
Forward voltage ⁽¹⁾	$I_F = 1.5A, T_J = 25^{\circ}C$		0.95	-	V
	I _F = 3.0A, T _J = 25°C	N	1.03	1.10	V
	I _F = 1.5A, T _J = 125°C	VF	0.84	-	V
	$I_F = 3.0A, T_J = 125^{\circ}C$		0.94	-	V
Reverse current @ rated V _R ⁽²⁾	T _J = 25°C	1	-	1	μA
	T _J = 125°C	I _R	7	-	μA
Junction capacitance	1MHz, V _R = 4.0V	CJ	14	-	pF

Notes:

(1) Pulse test with PW = 0.3ms

(2) Pulse test with PW = 30ms

ORDERING INFORMATION			
ORDERING CODE	PACKAGE	PACKING	
S3JFSH	SOD-128	14,000 / Tape & Reel	

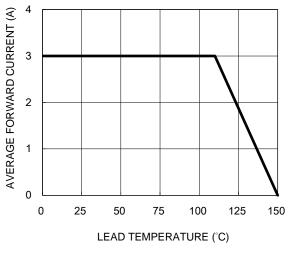


S3JFSH Taiwan Semiconductor

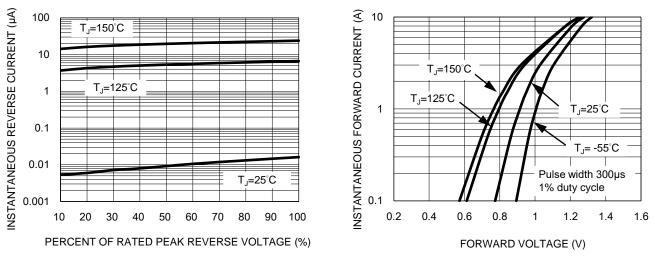
CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

Fig.1 Forward Current Derating Curve







100

10

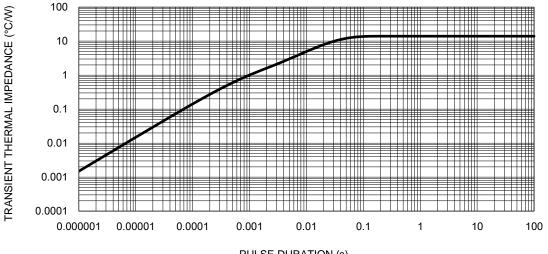
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f=1.0MHz Vsig=50mVp-p

CAPACITANCE (pF)





PULSE DURATION (s)

Fig.2 Typical Junction Capacitance

10

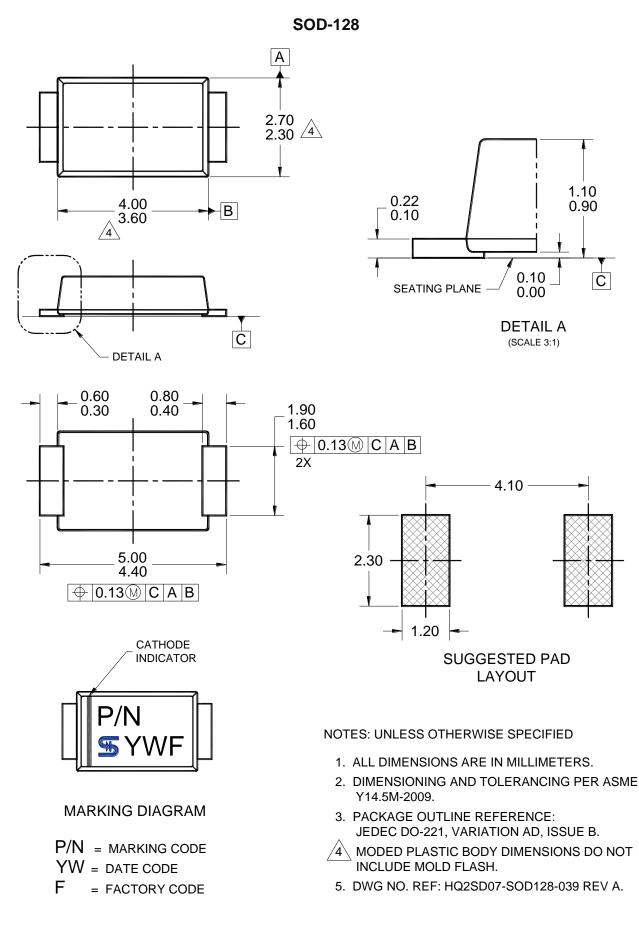
REVERSE VOLTAGE (V)

Fig.4 Typical Forward Characteristics

100



PACKAGE OUTLINE DIMENSIONS





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